Collector Base Voltage		60
Collector Emitter Voltage		50
Emitter Base Voltage		6
Collector Current		2
Collector Power Dissipation		0.5
Junction Temperature		150
Storage Temperature Range		- 55 to + 150

DC Current Gain at V_{CE} = 2 V, I_C =0.5 A at V_{CE} = 2 V, I_C = 1.5 A				
Collector Base Breakdown Voltage at I_C = 50 µA Collector Emitter Breakdown Voltage at I_C = 1 mA				
Emitter Base Breakdown Voltage at I_E = 50 µA				
Collector Cutoff Current at V_{CB} = 60 V				
Emitter Cutoff Current at V_{EB} = 5 V				
Collector Emitter Saturation Voltage at I_C = 1 A, I_B = 50 mA				
Output Capacitance at V_{CB} = 10 V, f = 1 MHz				
Transition Frequency at V_{CE} = 5 V, -I_E = 0.5 A, f = 100 MHz				

	82–180	120–200	
	DKP	DKQ	